

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,852,430 B2

Page 1 of 1

APPLICATION NO. : 10/059780

DATED : ~~January 29, 2002~~ February 8, 2005

INVENTOR(S) : Bian et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 8, lines 9 and 10
Claim 1, ~~B2A~~ should read:

--a seed layer of RuAl with a B2 crystallographic structure over the layer of CrTi;--

Column 8, lines 19 and 20
Claim 3, should read:

--3. The magnetic thin film disk of claim 1 wherein the CrTi layer has from 43 to 85 at % Ti.--

This certificate supersedes certificate of correction
issued February 12, 2004.

~~Signed and Sealed This~~

~~Twentieth Day of February 2005~~

~~By _____~~
~~Director, United States Patent and Trademark Office~~